

GreenPAK ™

3.3V-3.6V changeable 600mA LDO

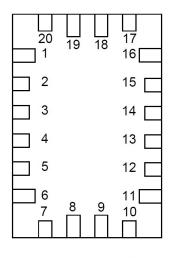
General Description

Pin Configuration

Renesas SLG7RN47205 is a low power and small form device. The SoC is housed in a 2mm x 3mm STQFN package which is optimal for using with small devices.

Features

- Low Power Consumption
- Pb Free / RoHS Compliant
- Halogen Free
- STQFN 20 Package



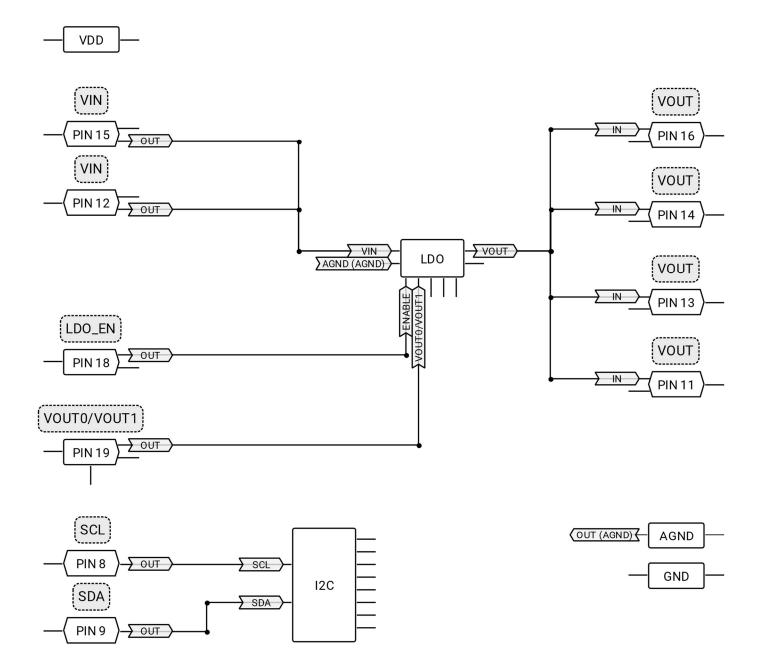
STQFN-20 (Top view)

Pin Name

Pin #	Pin name	Pin #	Pin name
1	NC	11	VOUT
2	NC	12	VIN
3	NC	13	VOUT
4	NC	14	VOUT
5	NC	15	VIN
6	NC	16	VOUT
7	VDD	17	AGND
8	SCL	18	LDO_EN
9	SDA	19	VOUT0/VOUT1
10	NC	20	GND



Block Diagram



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Pin #	Pin Name	Туре	Pin Description	Internal Resistor
1	NC		Keep Floating or Connect to GND	
2	NC		Keep Floating or Connect to GND	
3	NC		Keep Floating or Connect to GND	
4	NC		Keep Floating or Connect to GND	
5	NC		Keep Floating or Connect to GND	
6	NC		Keep Floating or Connect to GND	
7	VDD	PWR	Supply Voltage	
8	SCL	Digital Input	Digital Input without Schmitt trigger	floating
9	SDA	Digital Input	Digital Input without Schmitt trigger	floating
10	NC		Keep Floating or Connect to GND	
11	VOUT	Analog Output	LDO VOUT Analog Output	floating
12	VIN	Analog Input	LDO VIN Analog Input	floating
13	VOUT	Analog Output	LDO VOUT Analog Output	floating
14	VOUT	Analog Output	LDO VOUT Analog Output	floating
15	VIN	Analog Input	LDO VIN Analog Input	floating
16	VOUT	Analog Output	LDO VOUT Analog Output	floating
17	AGND	AGND	Ground	
18	LDO_EN	Digital Input	Digital Input without Schmitt trigger	1MΩ pulldown
19	VOUT0/VOUT1	Digital Input	Digital Input without Schmitt trigger	1MΩ pulldown
20	GND	GND	Ground	

Ordering Information

Part Number	Package Type
SLG7RN47205V	20-pin STQFN - Tape and Reel (3k units)



Absolute Maximum Conditions

Parameter	Min.	Max.	Unit
Supply Voltage on VDD relative to GND	-0.3	7	V
DC Input Voltage	GND - 0.5V	VDD + 0.5V	V
Current at Input Pin	-1.0	1.0	mA
Input leakage (Absolute Value)		1000	nA
Storage Temperature Range	-65	150	°C
Junction Temperature		150	°C
ESD Protection (Human Body Model)	2000		V
ESD Protection (Charged Device Model)	1300		V
Moisture Sensitivity Level		1	

Electrical Characteristics

Symbol	Parameter	Condition/Note	Min.	Тур.	Max.	Unit
Vdd	Supply Voltage		3.9	5	5.5	V
TA	Operating Temperature		-40	25	85	°C
CVDD	Capacitor Value at VDD			0.1		μF
CIN	Input Capacitance			4		pF
lq	Quiescent Current	Static inputs and floating outputs. PINs 12 and 15 are LOW, PINs 8 and 9 are HIGH		1		μA
Vo	Maximal Voltage Applied to any PIN in High- Impedance State				VDD+0.3	V
	Maximum Average or DC Current Through VDD Pin	T _J = 85°C			73	mA
IVDD	(Per chip side, see Note 2)	T _J = 110°C			35	mA
	Maximum Average or DC Current Through GND Pin	T _J = 85°C			152	mA
IGND	(Per chip side, see Note 2)	T _J = 110°C			72	mA
VIH	HIGH-Level Input Voltage	Logic Input	0.7xVDD		VDD+0.3	V
VIL	LOW-Level Input Voltage	Logic Input	GND-0.3		0.3xVDD	V
Rpull_down	Internal Pull Down Resistance	Pull down on PINs 18, 19		1		MΩ
		Vout0 voltage		3.30		V
LDO0	LDO0 output voltage	Vout1 voltage		3.60		V
Tsu	Startup Time	From VDD rising past PONTHR		1.3		ms
PONTHR	Power On Threshold	V _{DD} Level Required to Start Up the Chip	1.34	1.55	1.74	V
POFFTHR	Power Off Threshold	V _{DD} Level Required to Switch Off the Chip	1.05	1.25	1.45	V

Note:

 DC or average current through any pin should not exceed value given in Absolute Maximum Conditions.
The GreenPAK's power rails are divided in two sides. PINs 1, 2, 3, 4, 5 and 6 are connected to one side, PINs 8, 9, 10, 18 and 19 to another.

3. Guaranteed by Design.



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I²C Specifications

Symbol	Parameter	Condition/Note	Min.	Тур.	Max.	Unit
F _{SCL}	Clock Frequency, SCL	V _{DD} = (2.35.5) V			400	kHz
t _{LOW}	Clock Pulse Width Low	V _{DD} = (2.35.5) V	1300			ns
t _{ніGH}	Clock Pulse Width High	V _{DD} = (2.35.5) V	600			ns
t .	Input Filter Spike	$V_{DD} = 3.3V \pm 10\%$			95	ns
tı	Suppression (SCL, SDA)	$V_{DD} = 5.0V \pm 10\%$			111	ns
taa	Clock Low to Data Out Valid	V _{DD} = (2.35.5) V			900	ns
t _{BUF}	Bus Free Time between Stop and Start	V _{DD} = (2.35.5) V 1300 -				ns
thd_sta	Start Hold Time	V _{DD} = (2.35.5) V	600			ns
tsu_sta	Start Set-up Time	V _{DD} = (2.35.5) V	600			ns
thd_dat	Data Hold Time	V _{DD} = (2.35.5) V	0			ns
tsu_dat	Data Set-up Time	V _{DD} = (2.35.5) V	100			ns
t _R	Inputs Rise Time	V _{DD} = (2.35.5) V			300	ns
t⊧	Inputs Fall Time	V _{DD} = (2.35.5) V			300	ns
tsu_sто	Stop Set-up Time	V _{DD} = (2.35.5) V	600			ns
t _{DH}	Data Out Hold Time	V _{DD} = (2.35.5) V	50			ns

LDO Regulator Thermal Limitations

Symbol	Parameter	Condition/Note	Min.	Тур.	Max.	Unit
ICτι		85 °C ambient, Total IC package			0.6	W
		70 °C ambient, Total IC package			0.8	W
	Thermal Shutdown ¹		89	103	117	°C
Shutdown ²	Thermal Shutdown		83	87	91	°C
Note:	Recovery					<u> </u>

1. Lower Thermal shutdown levels may be achieved by using the temperature sensor and comparator.

2. TA = 85 °C.

LDO HP MODE Electrical Specifications at T = 25°C

Symbol	Parameter	Condition/Note	Min.	Тур.	Max.	Unit
Іоит	Output Current Rating				600	mA
VIN	Voltage Input		2.3		VDD	V
Vdo	Voltage Dropout			250	300	mV
ΔVουτ	Output Voltage Accuracy	over PVT of V _{OUT} > 1.5 V	-3		+3	%
Δνουι	(see Note 1)	over PVT of V _{OUT} ≤ 1.5 V	-60		+60	mV
en	Noise Voltage (rms)	10 Hz to 100 kHz		75		μV
PSRR	Power Supply Rejection Ratio (see Note 2)	100 Hz to 100 kHz		50		dB
CTRR	Crosstalk Rejection Ratio			50		dB
ΔV_{LINE}	Line Regulation	V_{OUT} + 0.5 V < $V_{IN} \le 5.5$ V	-1%		+1%	%/V
ΔV_{LOAD}	Load Regulation	1 mA < I _{OUT} < 600 mA			0.075	mV/ mA
ΔVτc	Vout Temp Coefficient			100		ppm/ C
CIN	External Input Capacitor (see Note 2)		4			μF



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Соит	External Output Capacitor (see Note 2)		8		 μF
SS0	SS Slew Rate 0	V _{OUT} = 5% to 95%		10	 V/ms
SS1	SS Slew Rate 1	V _{OUT} = 5% to 95%		20	 V/ms
SS2	SS Slew Rate 2	V _{OUT} = 5% to 95%		1.25	 V/ms
SS3	SS Slew Rate 3	V _{OUT} = 5% to 95%		2.50	 V/ms
twait	Wait Time	Time from EN=1 to V _{OUT} start rise		420	 μs
Note:					

1. Accuracy specifies all the effects of line regulation (ΔV_{LINE}), load regulation (ΔV_{LOAD}), and temperature coefficient (ΔV_{TC}),

2. X7R-type and X5R-type capacitors are recommended

Chip Address

HEX	BIN	DEC
0x08	0001000	8





Description

PIN 18 (LDO_EN)	PIN19 (VOUT0/VOUT1)	LDO status
L	L	Disabled
L	Н	Disabled
Н	L	Active output 3.3V
Н	Н	Active output 3.6V





I2C Description

1. I2C Basic Command Structure

Each command to the I2C Serial Communications block begins with a Control Byte. The bits inside this Control Byte are shown in Figure 1. After the Start bit, the first four bits are a control code, which can be set by the user in reg<1867:1864>. The Block Address is the next three bits (A10, A9, A8), which will define the most significant bits in the addressing of the data to be read ("1") or written ("0") by the command. This Control Byte will be followed by an Acknowledge bit (ACK).

With the exception of the Current Address Read command, all commands will have the Control Byte followed by the Word Address. The Word Address, in conjunction with the three address bits in the Control Byte, will define the specific data byte to be read or written in the command. Figure 1 shows this basic command structure.

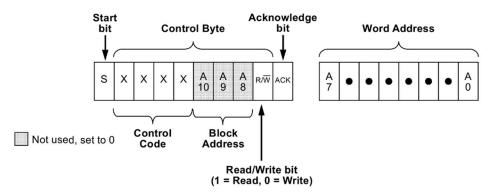


Figure 1. I2C Basic Command Structure

2. I2C Serial General Timing

Shown in Figure 2 is the general timing characteristics for the I2C Serial Communications block.

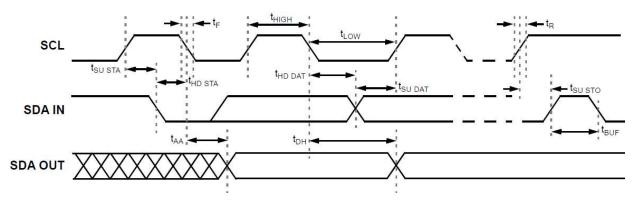


Figure2. I2C Serial General Timing



3. I2C Serial Communications: Read and Write Commands

Following the Start condition from the master, the Control Code [4 bits], the block address [3 bits] and the R/W bit (set to "0"), is placed onto the bus by the Bus Master. After the I2C Serial Communications block has provided an Acknowledge bit (ACK) the next byte transmitted by the master is the Word Address. The Block Address is the next three bits, and is the higher order addressing bits (A10, A9, A8), which when added to the Word Address will together set the internal address pointer in the SLG7RN47205 to the correct data byte to be written. After the SLG7RN47205 sends another Acknowledge bit, the Bus Master will transmit the data byte to be written into the addressed memory location. The SLG7RN47205 again provides an Acknowledge bit and then the Bus Master generates a Stop condition. The internal write cycle for the data will take place at the time that the SLG7RN47205 generates the Acknowledge bit.

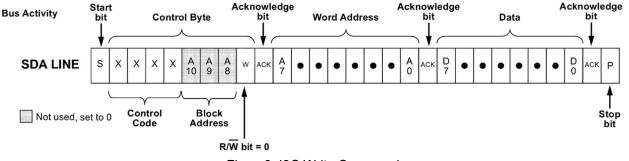
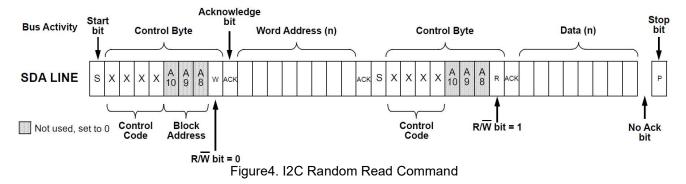


Figure 3. I2C Write Command

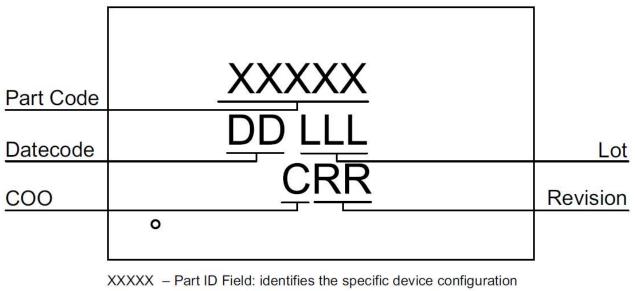
The Random Read command starts with a Control Byte (with R/\overline{W} bit set to "0", indicating a write command) and Word Address to set the internal byte address, followed by a Start bit, and then the Control Byte for the read (exactly the same as the Byte Write command). The Start bit in the middle of the command will halt the decoding of a Write command, but will set the internal address counter in preparation for the second half of the command. After the Start bit, the Bus

Master issues a second control byte with the R/\overline{W} bit set to "1", after which the SLG7RN47205 issues an Acknowledge bit, followed by the requested eight data bits.





Package Top Marking



DD – Date Code Field: Coded date of manufacture

LLL – Lot Code: Designates Lot #

C – Assembly Site/COO: Specifies Assembly Site/Country of Origin

RR – Revision Code: Device Revision

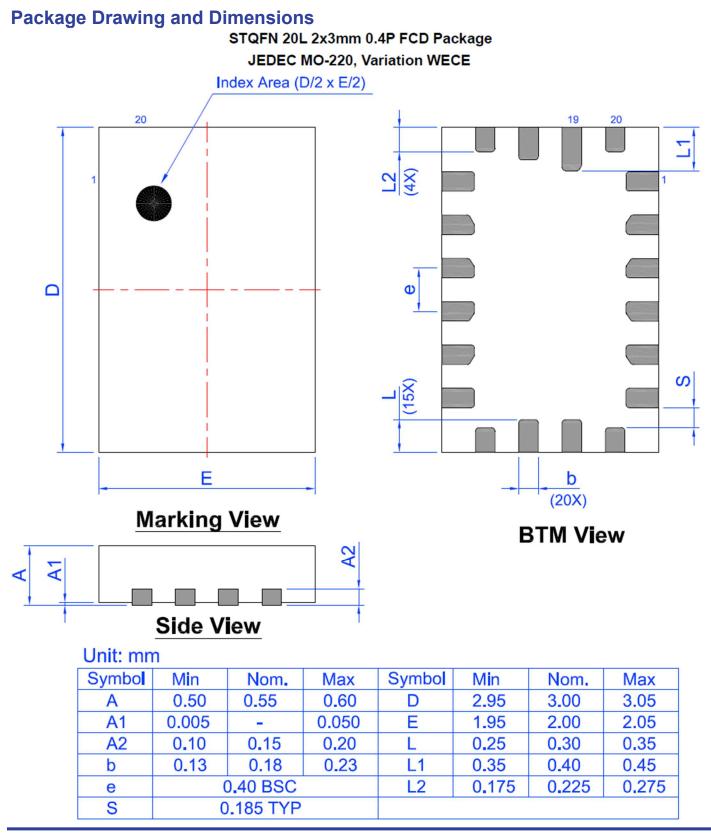
Datasheet Revision	Programming Code Number	Lock Status	Checksum	Part Code	Revision	Date
1.00	001	L	0xE261D6B	47205	AB	11/01/2024

Lock coverage for this part is indicated by $\sqrt{}$, from one of the following options:

Unlocked
Locked for read, bits <1535:0>
Locked for write, bits <1535:0>
Locked for write all bits
Locked for read and write bits <1535:0>
 Locked for read bits <1535:0> and write of all bits

The IC security bit is locked/set for code security for production unless otherwise specified. The Programming Code Number is not changed based on the choice of locked vs. unlocked status.





SLG7RN47205_DS_r100

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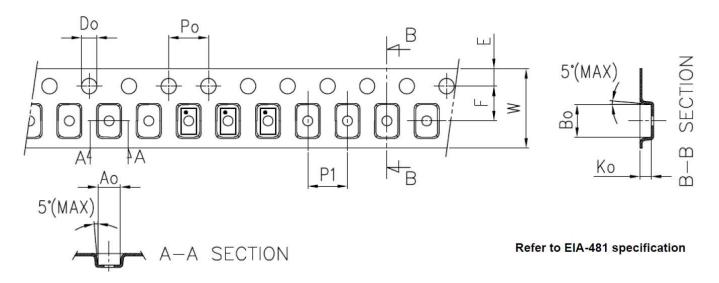
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Tape and Reel Specification

Package Type	# of Pins	Nominal Package Size [mm]	Max Units			Leader (min)		Trailer (min)		Таре	Part
			per Reel	per Box	Reel & Hub Size [mm]	Pockets	Length [mm]	Pockets	Length [mm]	Width [mm]	Pitch [mm]
STQFN 20L 2x3mm 0.4P FCD	20	2 x 3 x 0.55	3000	3000	178/60	100	400	100	400	8	4

Carrier Tape Drawing and Dimensions

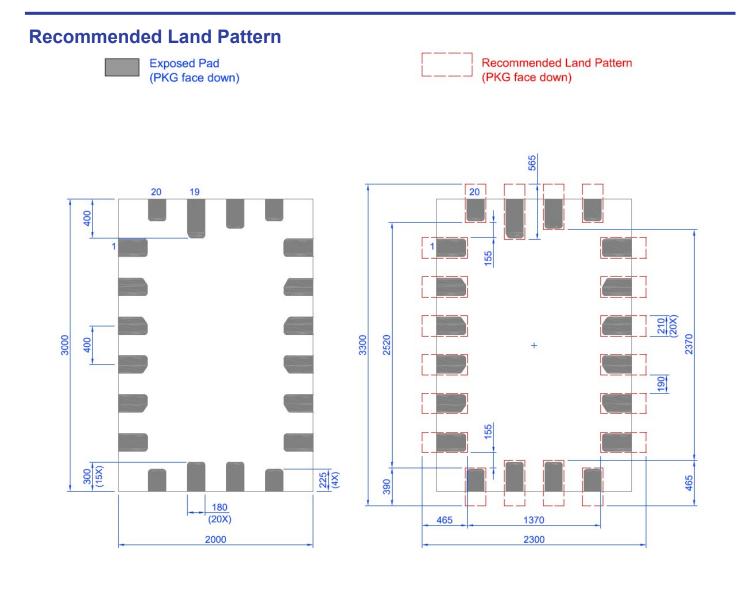
Package Type	Pocket BTM Length	Pocket BTM Width	Pocket Depth	Index Hole Pitch	Pocket Pitch	Index Hole Diameter	Index Hole to Tape Edge	Index Hole to Pocket Center	Tape Width
	A0	B0	K0	P0	P1	D0	E	F	w
STQFN 20L 2x3mm 0.4P FCD	2.2	3.15	0.76	4	4	1.5	1.75	3.5	8



Recommended Reflow Soldering Profile

Please see IPC/JEDEC J-STD-020: latest revision for reflow profile based on package volume of 3.30 mm³ (nominal). More information can be found at <u>www.jedec.org.</u>





Unit:um





Datasheet Revision History

Date	Version	Change				
12/12/2023	0.10	New design				
12/152023	0.11	Updated Device Revision Table				
10/25/2024	0.12	Locked design, deleted ASM Specifications table, added LDO Specification				
		table and Description, updated conditions for quiescent current measurement				
10/30/2024	0.13	Updated Device Revision Table				
11/01/2024	1.00	Production Release				



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